

ICOS

International Cooperation on Semiconductors

2nd ROK-EU Semiconductor Researcher Forum

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INTRODUCTION

• ICOS Project started in January 2023 for three years, it is funded by the Horizon Europe research program.

Coordinator



Technical co-Coordinator



 An ambitious project in the framework of the European strategy for semiconductors





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Motivation & Objectives

- Semiconductors & Semiconductor-based photonics are pivotal technologies for almost all existing industrial sectors, as demonstrated by the recent chips shortages
- International cooperation is key for speeding up technological innovation (e.g. ITRS/IRDS, IPSR-I, ECS-SRIA, NEREID), reducing cost by avoiding duplicated research, strengthening complex supply and value chains, and is encouraged by the new strategies of leading semiconductor countries
 - => To build **balanced semiconductor partnerships** with like-minded countries
 - => To set out cooperative framework on *initiatives of mutual interest*
 - => To identify and support the establishment of the **most promising scientific international** collaborations
 - => To support the growth of the European Semiconductor industry through **focused research alliances** based on awareness of advanced research activities
 - => To strengthen **Europe's and partner Country's positions** in global value chains in this area and to contribute to the **EU Chips Act, Green deal and Digital Agenda**







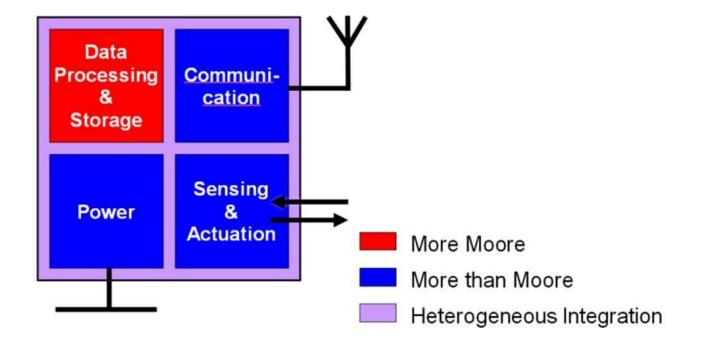
Objectives





Main scientific topics

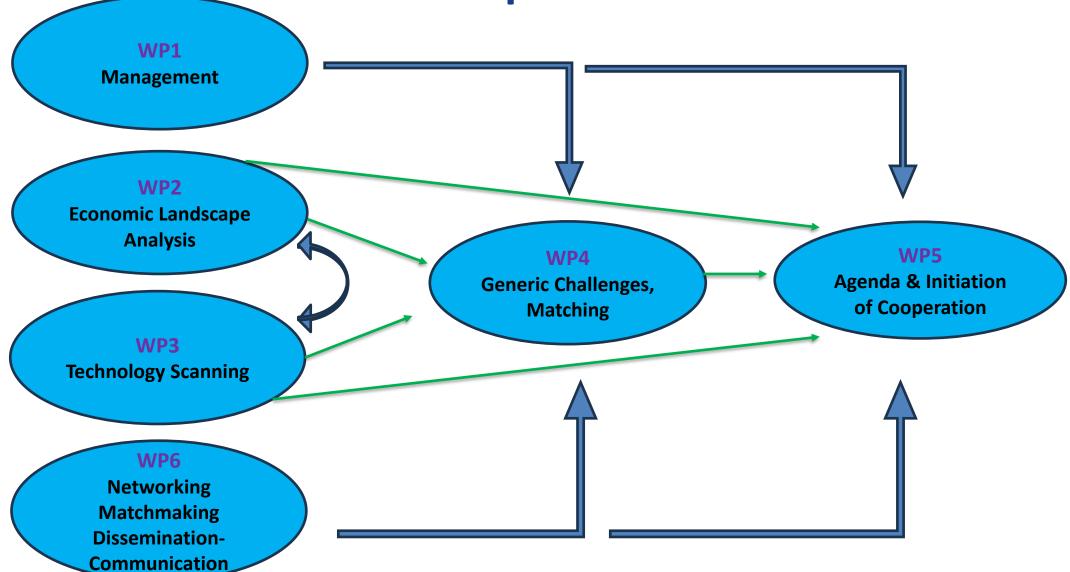
 Advanced computing & Advanced functionalities: sensing, RF & optical communications, optical devices, energy harvesting, power devices, ...



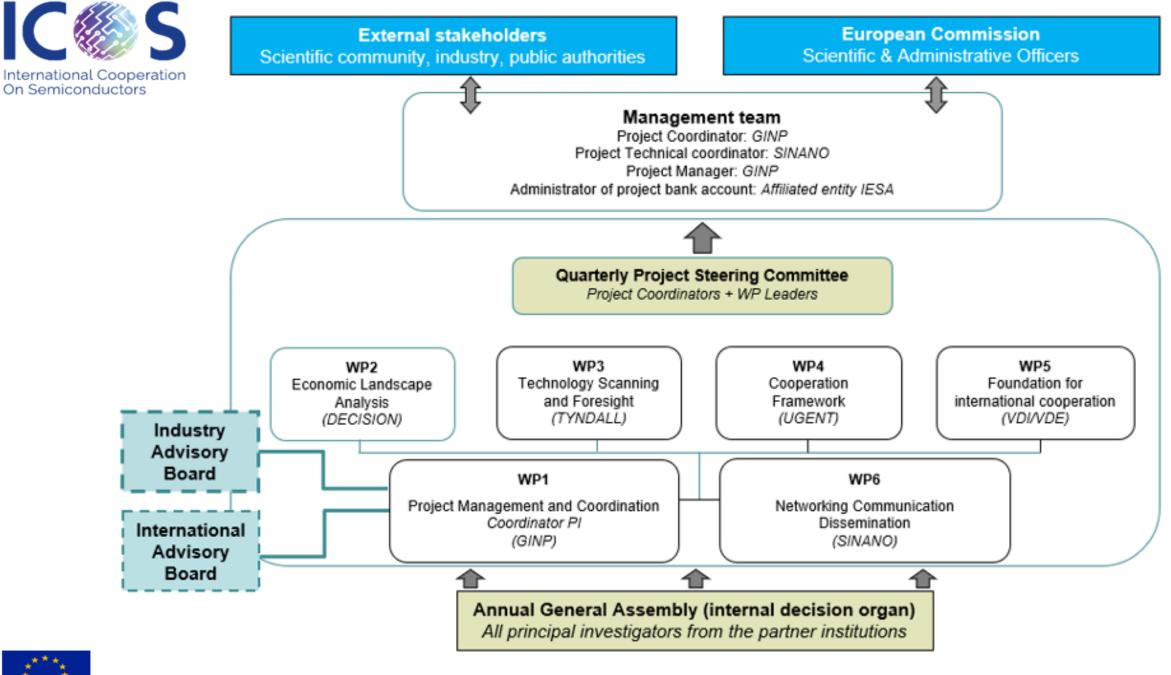




ICOS Concept









Structure of ICOS project & stakeholders



IMPLEMENTATION

IMPLEMENTATION -

EXHAUSTIVE ANALYSIS OF SEMICONDUCTORS' VALUE CHAINS, FOR ELECTRONICS & PHOTONICS

Identification of:

- EU's economic and industrial strengths & weaknesses
- Strategic dependencies
- Market and cooperation opportunities

AREAS FOR INTERNATIONAL COOPERATION

Identification of next generation & emerging technologies, especially in advanced computation and functionalities.

DETERMINATION OF MOST INTERESTING COUNTRIES FOR INTERNATIONAL COOPERATION

Identification of challenges for which international cooperation is critically important.

AGENDA FOR AND INITIATION OF INTERNATIONAL COOPERATIONS

- Dialogue with actors of existing cooperation
- International collaboration with non-EU national authorities
- Define standardisation needs and activities
- Support the European Commission





Challenges, possibles solutions & Collaboration opportunities: "Advanced computing"

- Classical' Logic Scaling Roadmap beyond FinFET technology that extends devices structures through **sub nm nodes** (e.g., **GAA and CFET architectures**)
- Exploration of 'Fully Depleted SOI' technology for Power Efficient Analog and RF applications
- Exploration of **alternative channel materials** (e.g., **2D** materials)
- Extension of the **scaling of BEOL technologies**, through the use of Ru, Airgap or Graphene-based metallization, by reducing the associated RC network
- Added BEOL functionality through the introduction of new materials such as 2D, oxide semiconductors and ferroics
- Exploration of the use of BEOL **Non-Volatile Memories** (using for example resistive RAM such as FeRAM, MRAM, PCRAM) to supplement/replace charge-based memories, for **in-memory computing** (eNVM), and for Power Efficient **Neuromorphic-based architectures**
- Photonic chips for optical interconnects and quantum information processing
- Demonstration of the capability of the 'Buried Power Rail delivery' to decongest the interconnection density that is becoming the most limiting factor for the scaling at 2nm and below
- Enablement of the High-NA EUV lithography for the patterning of 2nm nodes and beyond
- Usage of 3D integration to desegregate the classical large area chips into chiplets that will be much more power efficient when reconstruct using 3D integration design flow and associated toolbox
- Cryogenic electronics for power saving and quantum computing





Challenges & possible solutions & collaborations opportunities: "Advanced functionalities"

- Innovation in **new, highly sensitive and more versatile sensors** requiring more advanced sustainable (bio)materials innovation and integration
- For energy harvesters the improvement of the performance/ efficiency is as important as the development of "green" materials
- Wide band gap (e.g. SiC, GaN) and ultrawide band gap materials (e.g. AlN, GaOx, diamond) for power
- Flexible, Printable, Wearable Electronics: Future Hybridization of Flexible & Si-based electronics
- Heterogeneous integration of best materials for target application
- Advanced design tools, including multi-physics simulation for first-time-right modelling capabilities
- Rapid prototyping to bypass long chip iteration cycles (e.g. PDK, ADK availability)
- Packaging that meets multiple design requirements such as optical, electrical, mechanical, thermal, RF, (bio-)fouling etc.





Possible joint activities

- Webinars
- Workshops
- Contribution to Regional & International Technology Roadmaps (IRDS)
- International R&D&I cooperation on topics of mutual interests
- Exchange of researchers
- Access to Research Infrastructures
- Standardisation needs for emerging technologies





Thank you for your attention

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